





ZHCSBS6D - NOVEMBER 2013 - REVISED AUGUST 2024



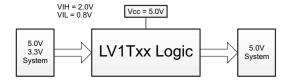


**SN74LV1T02** 

# SN74LV1T02 单电源 2 输入正或非门 CMOS 逻辑电平转换器

### 1 特性

- V<sub>CC</sub> 为 5.0V、3.3V、2.5V 和 1.8V 的单电源电压转
- 工作电压范围为 1.8V 至 5.5V
- 升压转换:
  - 1.8V V<sub>CC</sub> 时为 1.2V<sup>(1)</sup> 至 1.8V
  - 2.5V V<sub>CC</sub> 时为 1.5V<sup>(1)</sup> 至 2.5V
  - 3.3V V<sub>CC</sub> 时为 1.8V<sup>(1)</sup> 至 3.3V
  - 5.0V V<sub>CC</sub> 时为 3.3V 至 5.0V
- 降压转换:
  - 1.8V V<sub>CC</sub> 时为 3.3V 至 1.8V
  - 2.5V V<sub>CC</sub> 时为 3.3V 至 2.5V
  - 3.3V V<sub>CC</sub> 时 5.0V 至 3.3V
- 逻辑输出以 V<sub>CC</sub> 为基准
- 输出驱动:
  - 电压为 5V 时,输出驱动为 8mA
  - 电压为 3.3V 时,输出驱动为 7mA
  - 电压为 1.8V 时,输出驱动为 3mA
- 3.3V V<sub>CC</sub> 时,频率高达 50MHz
- 输入引脚可耐受 5V 电压
- -40°C 至 125°C 工作温度范围
- 可提供无铅封装: SC-70 (DCK)



- 2mm x 2.1mm x 0.65mm ( 高度 1.1mm )
- 闩锁性能超过 250mA, 符合 JESD 17 规范
- 支持标准逻辑引脚排列
- 与 AUP1G 和 LVC1G 系列兼容的 CMOS 输出 B<sup>1</sup>

### 2 应用

- 电信
- 便携式应用
- 服务器
- PC 和笔记本电脑

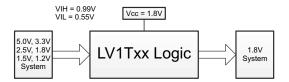
### 3 说明

SN74LV1T02 是一款具有较低输入阈值的单通道 2 输 入或非门,可支持电压转换应用。

#### 封装信息

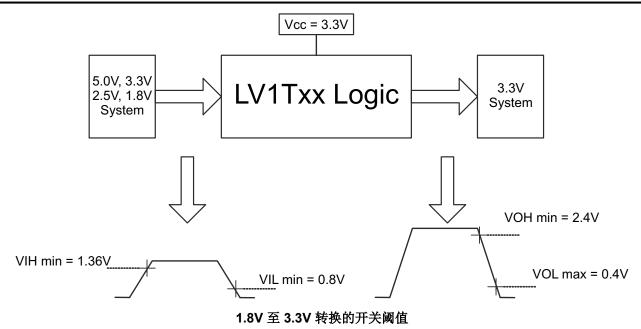
器件型号	封装 <sup>(1)</sup>	封装尺寸 <sup>(2)</sup>	本体尺寸(3)
SN74LV1T02	DBV ( SOT-23 , 5 )	2.90mm × 2.8mm	2.9mm x 1.6mm
3N/4EV1102	DCK ( SC-70 , 5 )	2.00mm × 2.1mm	2mm × 1.25mm

- 如需了解所有可用封装,请参阅数据表末尾的可订购产品附
- 封装尺寸(长×宽)为标称值,并包括引脚(如适用)。 (2)
- 本体尺寸(长x宽)为标称值,不包括引脚。



1 请参考较低 V<sub>CC</sub> 条件下的 V<sub>IH</sub>/V<sub>IL</sub> 和输出驱动。







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Product Folder Links: SN74LV1T02



### **4 Related Products**

DEVICE	PACKAGE	DESCRIPTION
SN74LV1T00	DCK, DBV	2-Input Positive-NAND Gate
SN74LV1T02	DCK, DBV	2-Input Positive-NOR Gate
SN74LV1T04	DCK, DBV	Inverter Gate
SN74LV1T08	DCK, DBV	2-Input Positive-AND Gate
SN74LV1T17	DCK, DBV	Single Schmitt-Trigger Buffer Gate
SN74LV1T14	DCK, DBV	Single Schmitt-Trigger Inverter Gate
SN74LV1T32	DCK, DBV	2-Input Positive-OR Gate
SN74LV1T34	DCK, DBV	Single Buffer Gate
SN74LV1T86	DCK, DBV	Single 2-Input Exclusive-Or Gate
SN74LV1T125	DCK, DBV	Single Buffer Gate with 3-state Output
SN74LV1T126	DCK, DBV	Single Buffer Gate with 3-state Output
SN74LV4T125	RGY, PW	Quadruple Bus Buffer Gate With 3-State Outputs

English Data Sheet: SCLS740



# **5 Pin Configuration and Functions**

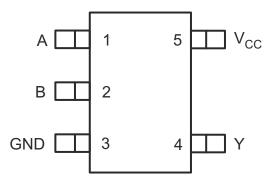


图 5-1. DCK or DBV Package, 5-Pin SC70 or SOT-23 (Top View)

表 5-1. Pin Functions

F	PIN	TYPE <sup>(1)</sup>	DESCRIPTION					
NAME	NO.	I I I PE('')	DESCRIPTION					
A	1	I	Input A					
В	2	I	Input B					
GND	3	G	Ground					
Y	4	0	Output Y					
V <sub>CC</sub>	5	Р	Positive supply					

<sup>(1)</sup> I = Input, O = Output, I/O = Input or Output, G = Ground, P = Power.

English Data Sheet: SCLS740



### 6 Specifications

### **6.1 Absolute Maximum Ratings**

over operating free-air temperature range (unless otherwise noted)(1)

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage range		- 0.5	7.0	V
VI	Input voltage range <sup>(2)</sup>		- 0.5	7.0	V
.,	Voltage range applied to a	any output in the high-impedance or power-off state <sup>(2)</sup>	- 0.5	4.6	V
Vo	Voltage range applied to a	any output in the high or low state <sup>(2)</sup>	- 0.5	V <sub>CC</sub> + 0.5	V
I <sub>IK</sub>	Input clamp current	V <sub>1</sub> < 0		- 20	mA
I <sub>OK</sub>	Output clamp current	$V_O < 0$ or $V_O > V_{CC}$		±20	mA
Io	Continuous output curren	t		±25	mA
	Continuous current through	h V <sub>CC</sub> or GND		±50	mA
TJ	Junction temperature			150	°C
T <sub>stg</sub>	Storage temperature		- 65	150	°C

<sup>(1)</sup> Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

### 6.2 ESD Ratings

			VALUE	UNIT
		Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>	±2000	
V <sub>(ESD)</sub>	Electrostatic discharge	Machine Model (MM), per JEDEC specification	±200	V
		Charged-device model (CDM), per ANSI/ESDA/JEDEC JS-002 <sup>(2)</sup>	±1000	

<sup>(1)</sup> JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

### **6.3 Recommended Operating Conditions**

over operating free-air temperature range (unless otherwise noted) (1)

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage		1.6	5.5	V
VI	Input voltage		0	5.5	V
Vo	Output voltage		0	V <sub>CC</sub>	V
		V <sub>CC</sub> = 1.8 V		- 3	
	High level output ourrent	V <sub>CC</sub> = 2.5 V		- 5	- 5 - 7 - 8
I <sub>OH</sub>	High-level output current	V <sub>CC</sub> = 3.3 V		- 7	
		V <sub>CC</sub> = 5.0 V		- 8	
		V <sub>CC</sub> = 1.8 V		3	
la.	Low-level output current	V <sub>CC</sub> = 2.5 V		5	mA
loL	Low-level output current	V <sub>CC</sub> = 3.3 V		7	ША
		V <sub>CC</sub> = 5.0 V		8	
		V <sub>CC</sub> = 1.8 V		20	
$\Delta$ t/ $\Delta$ v	Input transition rise or fall rate	V <sub>CC</sub> = 3.3 V or 2.5 V		20	ns/V
		V <sub>CC</sub> = 5.0 V		20	
T <sub>A</sub>	Operating free-air temperature		- 40	125	°C

<sup>(1)</sup> All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

Product Folder Links: SN74LV1T02

<sup>2)</sup> The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

<sup>(2)</sup> JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



### **6.4 Thermal Information**

	THERMAL METRIC(1)	DBV	DCK	UNIT
	THERMAL METRIC	5 PINS	5 PINS	ONIT
R <sub>0</sub> JA	Junction-to-ambient thermal resistance	278	289.2	°C/W

(1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.

### **6.5 Electrical Characteristics**

over recommended operating free-air temperature range (unless otherwise noted)

D^	RAMETER	TEST CONDITIONS	V <sub>CC</sub>	T <sub>A</sub> =	25°C		$T_A = -40^\circ$	C to +125°	°C	UNIT
PARAMETER		MIN TYP		MAX	MIN	I TYP MAX		CIVIT		
			V <sub>CC</sub> = 1.65 V to 1.8 V	0.94			1.0			
			V <sub>CC</sub> = 2.0 V	1.02			1.03			
			V <sub>CC</sub> = 2.25 V to 2.5 V	1.135			1.18			
,	High-level		V <sub>CC</sub> = 2.75 V	1.21			1.23			.,
V <sub>IH</sub>	input voltage		V <sub>CC</sub> = 3 V to 3.3 V	1.35			1.37			V
			V <sub>CC</sub> = 3.6 V	1.47			1.48			
			V <sub>CC</sub> = 4.5 V to 5.0 V	2.02			2.03			
			V <sub>CC</sub> = 5.5 V	2.1			2.11			
			V <sub>CC</sub> = 1.65 V to 2.0 V			0.58			0.55	
V <sub>IL</sub>	Low-level		V <sub>CC</sub> = 2.25 V to 2.75 V			0.75			0.71	V
V IL	input voltage		V <sub>CC</sub> = 3 V to 3.6 V			0.8			0.65	V
			V <sub>CC</sub> = 4.5 V to 5.5 V			0.8			0.8	
		I <sub>OH</sub> = -20 μA	1.65 V to 5.5 V	V <sub>CC</sub> - 0.1			V <sub>CC</sub> - 0.1			
		1 2.0 mA	1.65 V	1.28			1.21			
		I <sub>OH</sub> = -2.0 mA	1.8 V	1.5			1.45			
		I <sub>OH</sub> = -3 mA	2.3 V	2			1.93			
	High-level	I <sub>OH</sub> = -3 mA	2.5 V	2.25			2.15			
V <sub>OH</sub>	output	I <sub>OH</sub> = - 3.0 mA	3.0 V	2.78	,		2.7			V
	voltage	I <sub>OH</sub> = -5.5 mA	3.0 V	2.6			2.49			
		I <sub>OH</sub> = -5.5 mA	3.3 V	2.9			2.8			
		I <sub>OH</sub> = -4 mA		4.2			4.1			
		I <sub>OH</sub> = -8 mA	4.5 V	4.1			3.95			
		I <sub>OH</sub> = -8 mA	5.0 V	4.6			4.5			
		I <sub>OL</sub> = 20 μA	1.65 V to 5.5 V			0.1			0.1	
		I <sub>OL</sub> = 2 mA	1.65 V			0.2			0.25	
	Low-level	I <sub>OL</sub> = 3 mA	2.3 V			0.15			0.2	
V <sub>OL</sub>	output	I <sub>OL</sub> = 3 mA	0.01/			0.1			0.15	V
	voltage	I <sub>OL</sub> = 5.5 mA	3.0 V			0.2			0.252	
		I <sub>OL</sub> = 4 mA	4.5.7			0.15		,	0.2	
		I <sub>OL</sub> = 8 mA	4.5 V			0.3			0.35	
ı	Input leakage current	A input; V <sub>I</sub> = 0 V or V <sub>CC</sub>	0 V, 1.8 V, 2.5 V, 3.3 V, 5.5 V			0.1			±1	μА
			5.0 V			1			10	
	Static supply	$V_I = 0 \text{ V or } V_{CC}$	3.3 V			1			10	
I <sub>CC</sub>	current	I <sub>O</sub> = 0; open on loading	2.5 V			1			10	μА
			1.8 V			1			10	

Product Folder Links: SN74LV1T02



over recommended operating free-air temperature range (unless otherwise noted)

DAI	RAMETER	TEST CONDITIONS	V <sub>cc</sub>	T <sub>A</sub> = 2	25°C		T <sub>A</sub> = -40°	C to +125	5°C	UNIT
1 71	VANILILIX	TEST CONDITIONS	▼CC	MIN	TYP	MAX	MIN	TYP	MAX	OMIT
A 1	Additional	One input at 0.3 V or 3.4 V, Other inputs at 0 or V <sub>CC</sub> , I <sub>O</sub> = 0	5.5 V			1.35			1.5	mA
△ I <sub>CC</sub> static supply current	One input at 0.3 V or 1.1 V Other inputs at 0 or V <sub>CC</sub> , I <sub>O</sub> = 0	1.8 V			10			10	μА	
Ci	Input capacitance	V <sub>I</sub> = V <sub>CC</sub> or GND	3.3 V		2	10	2		10	pF
Co	Output capacitance	V <sub>O</sub> = V <sub>CC</sub> or GND	3.3 V		2.5		2.5			pF

### **6.6 Switching Characteristics**

over recommended operating free-air temperature range (unless otherwise noted) (see Parameter Measurement Information)

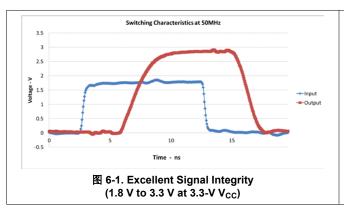
PARAMETER	FROM	то	FREQUENCY	V	CL	T	= 25°	С	T <sub>A</sub> = -6	5°C to	125°C	UNIT
PARAMETER	(INPUT)	(OUTPUT)	(TYP)	V <sub>CC</sub>	O <sub>L</sub>	MIN	TYP	MAX	MIN	TYP	MAX	ONII
				5.0 V	15 pF		4	5		4	5	ns
			DC to 50 MHz	3.0 V	30 pF		5.5	7.0		5.5	7.0	113
			DC to 30 Wil 12	3.3 V	15 pF		4.8	5		5	5.5	ns
	Any In	Y		3.5 V	30 pF	30 pF 5 5.5	5.5		5.5	6.5	115	
t <sub>pd</sub>	Any In	I I	DC to 25 MHz	2.5 V	15 pF		6	6.5		7	7.5	ne
			DC to 23 Wil 12	2.5 V	30 pF		6.5	7.5		7.5	8.5	ns
			DC to 15 MHz	Hz 1.8 V	15 pF		10.5	11		11	12	
					30 pF		12	13		12	14	ns

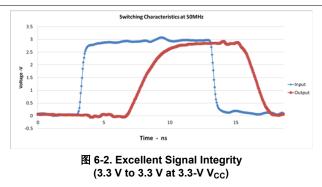
## **6.7 Operating Characteristics**

 $T_A = 25^{\circ}C$ 

	PARAMETER	TEST CONDITIONS	V <sub>cc</sub>	TYP	UNIT
			1.8 V ± 0.15 V	14	
C Power dissipation canacitan	Dower dissipation capacitance	f = 1 MHz and 10 MHz	2.5 V ± 0.2 V	14	pF
Opd	C <sub>pd</sub> Power dissipation capacitance	I = 1 MHZ and 10 MHZ	3.3 V ± 0.3 V	14	рг
			5.5 V ± 0.5 V	14	

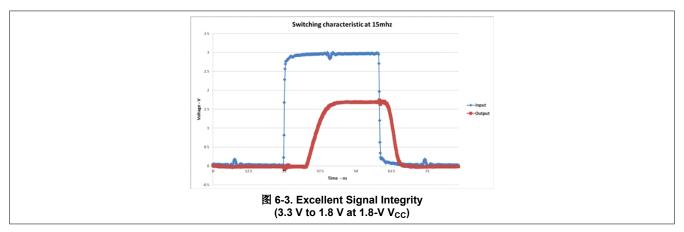
### **6.8 Typical Characteristics**





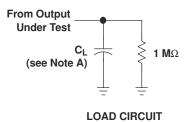


## **6.8 Typical Characteristics (continued)**

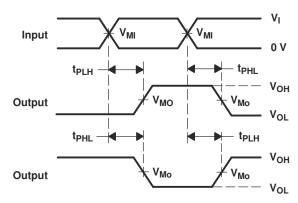




### 7 Parameter Measurement Information



	V <sub>CC</sub> = 2.5 V ± 0.2 V	V <sub>CC</sub> = 3.3 V ± 0.3 V
C <sub>L</sub>	5, 10, 15, 30 pF	5, 10, 15, 30 pF
V <sub>MI</sub>	V <sub>I</sub> /2	V <sub>I</sub> /2
V <sub>MO</sub>	V <sub>CC</sub> /2	V <sub>CC</sub> /2



VOLTAGE WAVEFORMS
PROPAGATION DELAY TIMES
INVERTING AND NONINVERTING OUTPUTS

NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

- B. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50 \Omega$ , slew rate  $\geq$  1 V/ns.
- C. The outputs are measured one at a time, with one transition per measurement.
- D.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .

图 7-1. Load Circuit and Voltage Waveforms

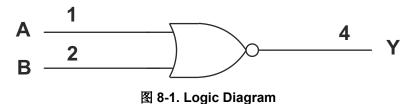
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### 8 Detailed Description

#### 8.1 Overview

The SN74LV1T02 device is a low-voltage CMOS gate logic that operates at a wider voltage range for industrial, portable, telecom, and automotive applications. The output level is referenced to the supply voltage and is able to support 1.8-V, 2.5-V, 3.3-V, and 5-V CMOS levels. The input is designed with a lower threshold circuit to match 1.8 V input logic at  $V_{CC}$  = 3.3 V and can be used in 1.8 V to 3.3 V level-up translation. In addition, the 5 V tolerant input pins enable down translation (that is, 3.3 V to 2.5 V output at  $V_{CC}$  = 2.5 V). The wide  $V_{CC}$  range of 1.8 V to 5.5 V allows generation of desired output levels to connect to controllers or processors. The SN74LV1T02 device is designed with current-drive capability of 8 mA to reduce line reflections, overshoot, and undershoot caused by high-drive outputs.

### 8.2 Functional Block Diagram



## 8.3 Feature Description

#### 8.3.1 Clamp Diode Structure

The outputs to this device have both positive and negative clamping diodes, and the inputs to this device have negative clamping diodes only as depicted in \bigseleq 8-2.

#### 小心

Voltages beyond the values specified in the Absolute Maximum Ratings table can cause damage to the device. The input and output voltage ratings may be exceeded if the input and output clampcurrent ratings are observed.

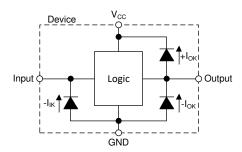


图 8-2. Electrical Placement of Clamping Diodes for Each Input and Output

#### 8.3.2 Balanced CMOS Push-Pull Outputs

This device includes balanced CMOS push-pull outputs. The term balanced indicates that the device can sink and source similar currents. The drive capability of this device may create fast edges into light loads so routing and load conditions should be considered to prevent ringing. Additionally, the outputs of this device are capable of driving larger currents than the device can sustain without being damaged. It is important for the output power of the device to be limited to avoid damage due to overcurrent. The electrical and thermal limits defined in the Absolute Maximum Ratings must be followed at all times.

Product Folder Links: SN74LV1T02

Unused push-pull CMOS outputs should be left disconnected.

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#### 8.3.3 LVxT Enhanced Input Voltage

The SN74LV1T02 belongs to Tl's LVxT family of Logic devices with integrated voltage level translation. This family of devices was designed with reduced input voltage thresholds to support up-translation, and inputs tolerant of signals with up to 5.5 V levels to support down-translation. The output voltage will always be referenced to the supply voltage ( $V_{CC}$ ), as described in the *Electrical Characteristics* table. To ensure proper functionality, input signals must remain at or below the specified  $V_{IH(MIN)}$  level for a HIGH input state, and at or below the specified  $V_{IL(MAX)}$  for a LOW input state. 8-3 shows the typical  $V_{IH}$  and  $V_{IL}$  levels for the LVxT family of devices, as well as the voltage levels for standard CMOS devices for comparison.

The inputs are high impedance and are typically modeled as a resistor in parallel with the input capacitance given in the *Electrical Characteristics*. The worst case resistance is calculated with the maximum input voltage, given in the *Absolute Maximum Ratings*, and the maximum input leakage current, given in the *Electrical Characteristics*, using Ohm's law  $(R = V \div I)$ .

The inputs require that input signals transition between valid logic states quickly, as defined by the input transition time or rate in the *Recommended Operating Conditions* table. Failing to meet this specification will result in excessive power consumption and could cause oscillations. More details can be found in the *Implications of Slow or Floating CMOS Inputs* application report.

Do not leave inputs floating at any time during operation. Unused inputs must be terminated at  $V_{CC}$  or GND. If a system will not be actively driving an input at all times, a pull-up or pull-down resistor can be added to provide a valid input voltage during these times. The resistor value will depend on multiple factors; however, a 10-k  $\Omega$  resistor is recommended and will typically meet all requirements.

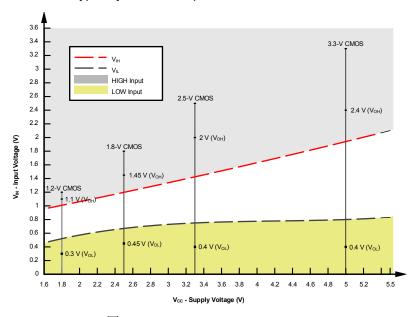


图 8-3. LVxT Input Voltage Levels

#### 8.3.3.1 Down Translation

Signals can be translated down using the SN74LV1T02. The voltage applied at the V<sub>CC</sub> will determine the output voltage and the input thresholds as described in the *Recommended Operating Conditions* and *Electrical Characteristics* tables.

When connected to a high-impedance input, the output voltage will be approximately  $V_{CC}$  in the HIGH state, and 0 V in the LOW state. Ensure that the input signals in the HIGH state are between  $V_{IH(MIN)}$  and 5.5 V, and input signals in the LOW state are lower than  $V_{IL(MAX)}$  as shown in  $\boxed{8}$  8-3.

For example, standard CMOS inputs for devices operating at 5.0 V, 3.3 V or 2.5 V can be down-translated to match 1.8 V CMOS signals when operating from 1.8-V  $V_{CC}$ . See  $\boxtimes$  8-4.

#### **Down Translation Combinations:**

- 1.8-V V<sub>CC</sub> Inputs from 2.5 V, 3.3 V, and 5.0 V
- 2.5-V  $V_{CC}$  Inputs from 3.3 V and 5.0 V
- 3.3-V V<sub>CC</sub> Inputs from 5.0 V

#### 8.3.3.2 Up Translation

Input signals can be up translated using the SN74LV1T02. The voltage applied at  $V_{CC}$  will determine the output voltage and the input thresholds as described in the *Recommended Operating Conditions* and *Electrical Characteristics* tables. When connected to a high-impedance input, the output voltage will be approximately  $V_{CC}$  in the HIGH state, and 0 V in the LOW state.

The inputs have reduced thresholds that allow for input high-state levels which are much lower than standard values. For example, standard CMOS inputs for a device operating at a 5-V supply will have a  $V_{IH(MIN)}$  of 3.5 V. For the SN74LV1T02,  $V_{IH(MIN)}$  with a 5-V supply is only 2 V, which would allow for up-translation from a typical 2.5-V to 5-V signals.

Ensure that the input signals in the HIGH state are above  $V_{IH(MIN)}$  and input signals in the LOW state are lower than  $V_{IL(MAX)}$  as shown in  $\boxed{8}$  8-4.

#### Up Translation Combinations:

- 1.8-V V<sub>CC</sub> Inputs from 1.2 V
- 2.5-V V<sub>CC</sub> Inputs from 1.8 V
- \* 3.3-V  $V_{CC}$  Inputs from 1.8 V and 2.5 V
- 5.0-V V<sub>CC</sub> Inputs from 2.5 V and 3.3 V

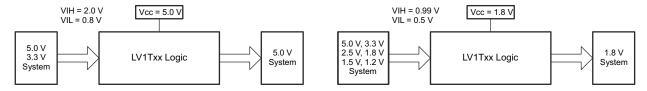


图 8-4. LVxT Up and Down Translation Example

#### 8.4 Device Functional Modes

#### **Function Table**

	UT <sup>(1)</sup> VEL INPUT)	OUTPUT <sup>(2)</sup> (V <sub>CC</sub> CMOS)							
Α	В	Υ							
Н	X	L							
X	Н	L							
L	L	Н							
	SUPPLY V <sub>CC</sub> = 3.3 V								
A	В	Y							
V <sub>IH</sub> (min) V <sub>IL</sub> (max)	= 1.35 V = 0.08 V	V <sub>OH</sub> (min) = 2.9 V V <sub>OL</sub> (max) = 0.2 V							

- H = High Voltage Level, L = Low Voltage Level, X = Do not Care, Z = High Impedance
- (2) H = Driving High, L = Driving Low, Z = High Impedance State

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### 9 Application and Implementation

#### 备注

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

#### 9.1 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the *Recommended Operating Conditions*. Each  $V_{CC}$  terminal should have a good bypass capacitor to prevent power disturbance. A 0.1-  $\mu$  F capacitor is recommended for this device. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. The 0.1-  $\mu$  F and 1-  $\mu$  F capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results, as shown in the following layout example.

#### 9.2 Layout

#### 9.2.1 Layout Guidelines

When using multiple-input and multiple-channel logic devices inputs must not ever be left floating. In many cases, functions or parts of functions of digital logic devices are unused; for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such unused input pins must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. All unused inputs of digital logic devices must be connected to a logic high or logic low voltage, as defined by the input voltage specifications, to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally, the inputs are tied to GND or V<sub>CC</sub>, whichever makes more sense for the logic function or is more convenient.

#### 9.2.2 Layout Example

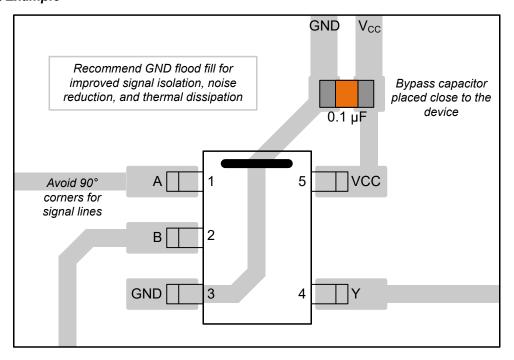


图 9-1. Example Layout for the SN74LV1T02

### 10 Device and Documentation Support

### 10.1 接收文档更新通知

要接收文档更新通知,请导航至 ti.com 上的器件产品文件夹。点击*通知* 进行注册,即可每周接收产品信息更改摘 要。有关更改的详细信息,请查看任何已修订文档中包含的修订历史记录。

### 10.2 支持资源

TI E2E™ 中文支持论坛是工程师的重要参考资料,可直接从专家处获得快速、经过验证的解答和设计帮助。搜索 现有解答或提出自己的问题,获得所需的快速设计帮助。

链接的内容由各个贡献者"按原样"提供。这些内容并不构成 TI 技术规范,并且不一定反映 TI 的观点;请参阅 TI的使用条款。

#### 10.3 Trademarks

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### 10.4 静电放电警告



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ESD 的损坏小至导致微小的性能降级,大至整个器件故障。精密的集成电路可能更容易受到损坏,这是因为非常细微的参 数更改都可能会导致器件与其发布的规格不相符。

### 10.5 术语表

TI术语表

本术语表列出并解释了术语、首字母缩略词和定义。

### 11 Revision History

注:以前版本的页码可能与当前版本的页码不同

Changes from Revision C (October 2023) to Revision D (August 2024)	Page
• Updated R θ JA values: DBV = 206 to 278, all values in °C/W	7
Added image in Layout Example section	14
Changes from Revision B (June 2022) to Revision C (October 2023)	Page
• Updated R θ JA values: DCK = 252 to 289.2, all values in °C/W	7

## 12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

Product Folder Links: SN74LV1T02

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#### PACKAGING INFORMATION

Orderable part number	Status	Material type	Package   Pins	Package qty   Carrier	RoHS	Lead finish/	MSL rating/	Op temp (°C)	Part marking
	(1)	(2)			(3)	Ball material	Peak reflow		(6)
						(4)	(5)		
SN74LV1T02DBVR	Active	Production	SOT-23 (DBV)   5	3000   LARGE T&R	Yes	NIPDAU   SN   NIPDAU	Level-1-260C-UNLIM	-40 to 125	(3JRH, NEB3, NEBJ, NEBS)
SN74LV1T02DBVR.A	Active	Production	SOT-23 (DBV)   5	3000   LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	(3JRH, NEB3, NEBJ, NEBS)
SN74LV1T02DBVRG4	Active	Production	SOT-23 (DBV)   5	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	NEB3
SN74LV1T02DBVRG4.A	Active	Production	SOT-23 (DBV)   5	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	NEB3
SN74LV1T02DCKR	Active	Production	SC70 (DCK)   5	3000   LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	(1QW, WB3, WBJ, WB S)
SN74LV1T02DCKR.A	Active	Production	SC70 (DCK)   5	3000   LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	(1QW, WB3, WBJ, WB S)
SN74LV1T02DCKRG4	Active	Production	SC70 (DCK)   5	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-	WB3
SN74LV1T02DCKRG4.A	Active	Production	SC70 (DCK)   5	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	WB3

<sup>(1)</sup> Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

<sup>(2)</sup> Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

<sup>(4)</sup> Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

## PACKAGE OPTION ADDENDUM

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

#### OTHER QUALIFIED VERSIONS OF SN74LV1T02:

Automotive: SN74LV1T02-Q1

NOTE: Qualified Version Definitions:

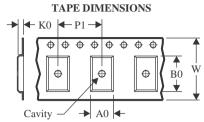
Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

## **PACKAGE MATERIALS INFORMATION**

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### TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LV1T02DBVR	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
SN74LV1T02DBVRG4	SOT-23	DBV	5	3000	178.0	9.2	3.3	3.23	1.55	4.0	8.0	Q3
SN74LV1T02DCKR	SC70	DCK	5	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
SN74LV1T02DCKRG4	SC70	DCK	5	3000	178.0	9.2	2.4	2.4	1.22	4.0	8.0	Q3

# **PACKAGE MATERIALS INFORMATION**

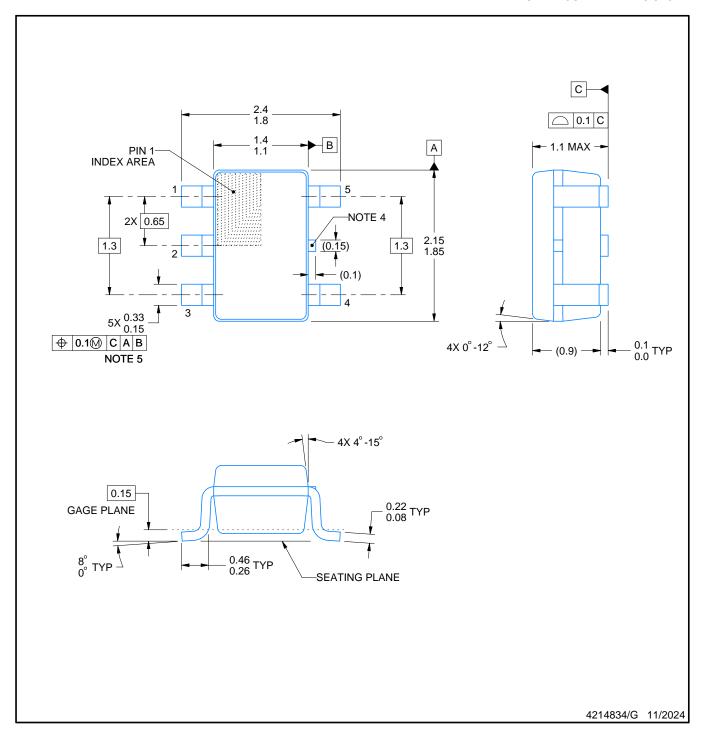
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#### \*All dimensions are nominal

7 til dillioliolollo dio Hollilla							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LV1T02DBVR	SOT-23	DBV	5	3000	210.0	185.0	35.0
SN74LV1T02DBVRG4	SOT-23	DBV	5	3000	180.0	180.0	18.0
SN74LV1T02DCKR	SC70	DCK	5	3000	180.0	180.0	18.0
SN74LV1T02DCKRG4	SC70	DCK	5	3000	180.0	180.0	18.0



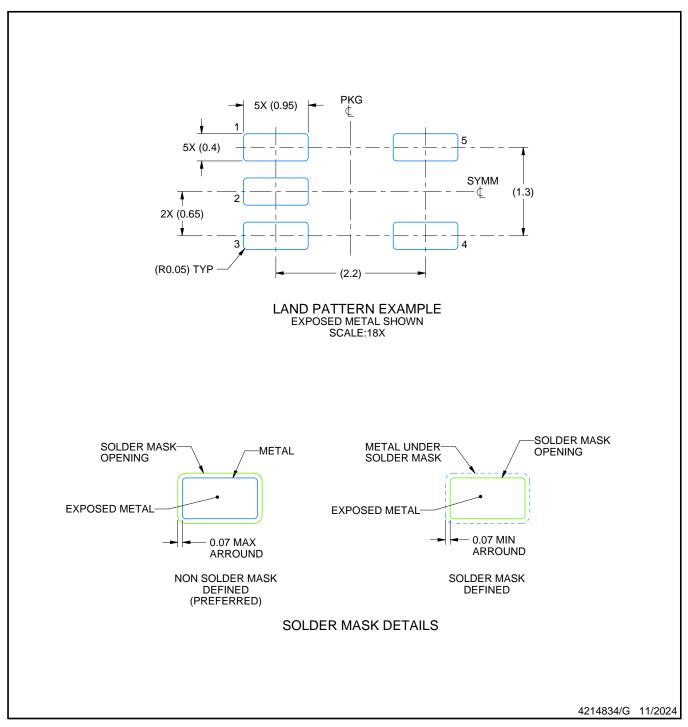


#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
  2. This drawing is subject to change without notice.
  3. Reference JEDEC MO-203.

- 4. Support pin may differ or may not be present.5. Lead width does not comply with JEDEC.
- 6. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25mm per side

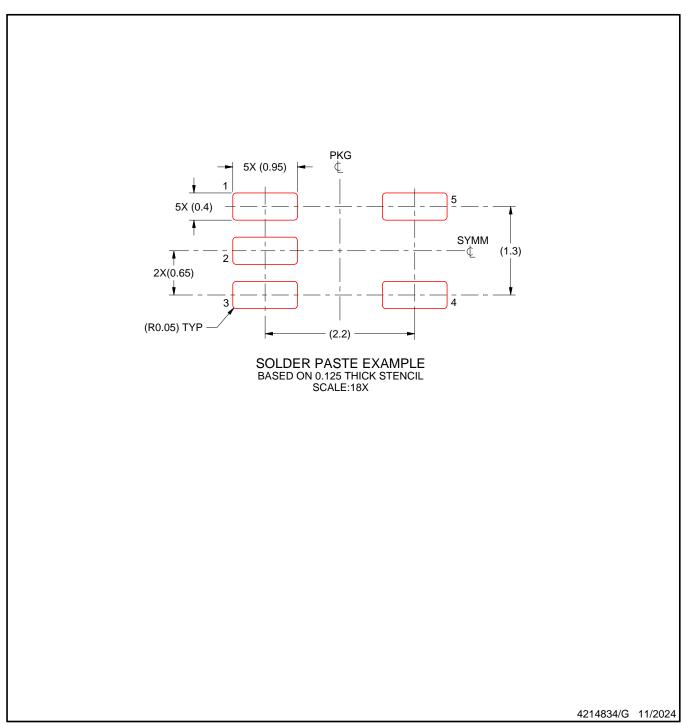




NOTES: (continued)

7. Publication IPC-7351 may have alternate designs.8. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 9. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 10. Board assembly site may have different recommendations for stencil design.







#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
  2. This drawing is subject to change without notice.
  3. Reference JEDEC MO-178.

- 4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.
- 5. Support pin may differ or may not be present.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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